CBCP68 NPN CBCP69 PNP

SURFACE MOUNT SILICON COMPLEMENTARY SMALL SIGNAL TRANSISTORS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CBCP68 and CBCP69 are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for applications requiring high current capability.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Emitter Voltage	V _{CES}	25	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	IC	1.0	Α
Peak Collector Current	I _{CM}	2.0	Α
Continuous Base Current	I_{B}	100	mA
Peak Base Current	I _{BM}	200	mA
Power Dissipation	P_{D}	2.0	W
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	$\Theta_{\sf JA}$	62.5	°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

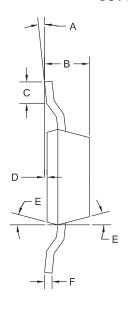
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TEST CONDITIONS	MIN	TYP	MAX	UNITS			
V _{CB} =25V			10	μΑ			
V _{CB} =25V, T _A =150°C			1.0	mA			
V _{EB} =5.0V			10	μΑ			
I _C =10μA	25			V			
I _C =10mA	20			V			
I _E =1.0μA	5.0			V			
I _C =1.0A, I _B =100mA			0.5	V			
V _{CE} =10V, I _C =5.0mA		0.6		V			
V _{CE} =1.0V, I _C =1.0A			1.0	V			
V _{CE} =10V, I _C =5.0mA	50						
V _{CE} =1.0V, I _C =500mA	85		375				
V _{CE} =1.0V, I _C =1.0A	60						
V_{CE} =5.0V, I_{C} =10mA, f=20MHz	65			MHz			
V_{CB} =5.0V, I_{E} =0, f=450kHz		25		pF			
	V _{CB} =25V V _{CB} =25V, T _A =150°C V _{EB} =5.0V I _C =10µA I _C =1.0µA I _C =1.0A, I _B =100mA V _{CE} =1.0V, I _C =5.0mA V _{CE} =1.0V, I _C =1.0A	TEST CONDITIONS V _{CB} =25V V _{CB} =25V, T _A =150°C V _{EB} =5.0V I _C =10μA I _C =1.0μA I _C =1.0μA I _C =1.0A, I _B =100mA V _{CE} =10V, I _C =5.0mA V _{CE} =1.0V, I _C =5.0mA Solution Solution Solution V _{CE} =1.0V, I _C =5.0mA Solution Solutio	TEST CONDITIONS V _{CB} =25V V _{CB} =25V, T _A =150°C V _{EB} =5.0V I _C =10μA I _C =10μA I _C =1.0μA I _C =1.0μA I _C =1.0A, I _B =100mA V _{CE} =10V, I _C =5.0mA V _{CE} =1.0V, I _C =5.0mA Solution V _{CE} =1.0V, I _C =5.0mA V _{CE} =1.0V, I _C =5.0mA Solution V _{CE} =1.0V, I _C =5.0mA Solution Solution O.6 V _{CE} =1.0V, I _C =5.00mA O.6 V _{CE} =1.0V, I _C =5.00mA O.6 OCE=1.0V, I _C =5.00mA OCE=1.0V, I _C =5.00mA OCE=1.0V, I _C =1.00A OCE=5.0V, I _C =1.00A OCE=5.0V, I _C =1.00A, f=20MHz	TEST CONDITIONS MIN TYP MAX V _{CB} =25V 10 V _{CB} =25V, T _A =150°C 1.0 V _{EB} =5.0V 10 I _C =10µA 25 I _C =10mA 20 I _E =1.0µA 5.0 I _C =1.0A, I _B =100mA 0.5 V _{CE} =10V, I _C =5.0mA 0.6 V _{CE} =1.0V, I _C =5.0mA 50 V _{CE} =1.0V, I _C =5.0mA 85 V _{CE} =1.0V, I _C =1.0A 60 V _{CE} =5.0V, I _C =10mA, f=20MHz 65			

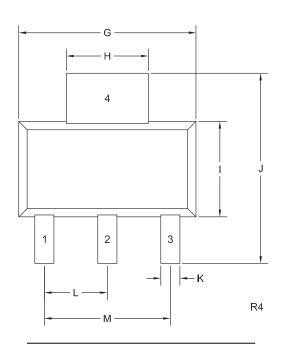
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SOT-223 CASE - MECHANICAL OUTLINE





LEAD CODE:

- 1) Base
- 2) Collector
- 3) Emitter
- 4) Collector

MARKING:

FULL PART NUMBER

DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0°	10°	0°	10°		
В	0.059	0.071	1.50	1.80		
С	0.018		0.45			
D	0.000	0.004	0.00	0.10		
Е	10°		10°			
F	0.009	0.014	0.23	0.35		
G	0.248	0.264	6.30	6.70		
Н	0.114	0.122	2.90	3.10		
	0.130	0.146	3.30	3.70		
J	0.264	0.287	6.70	7.30		
K	0.024	0.033	0.60	0.85		
L	0.091		2.30			
М	0.181			60		

SOT-223 (REV: R4)

R6 (4-August 2017)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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